

TOSHIBA TRANSISTOR SILICON PNP TRIPLE DIFFUSED TYPE

# 2SA1924

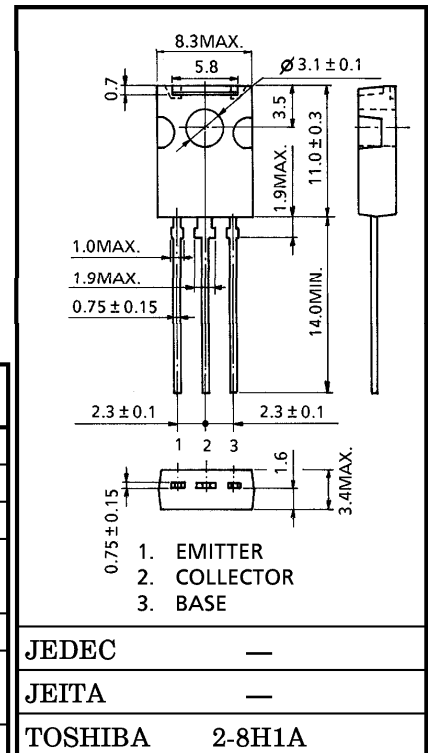
HIGH VOLTAGE SWITCHING APPLICATIONS

- High Voltage :  $V_{CEO} = -400\text{ V}$
- Low Saturation Voltage :  $V_{CE(sat)} = -1\text{ V (Max.)}$   
( $I_C = -100\text{ mA}$ ,  $I_B = -10\text{ mA}$ )
- Collector Metal (Fin) is Fully Covered with Mold Resin

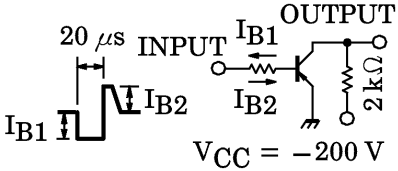
MAXIMUM RATINGS ( $T_c = 25^\circ\text{C}$ )

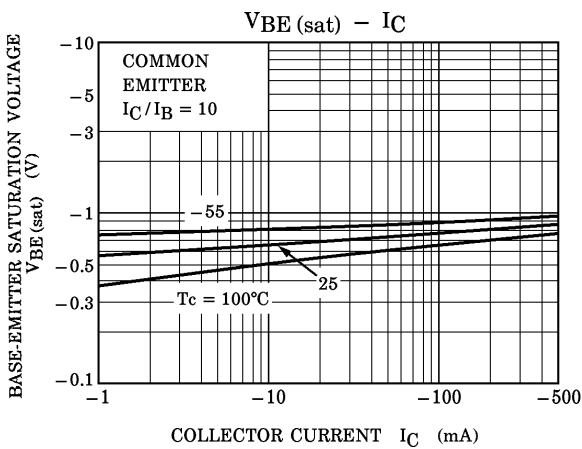
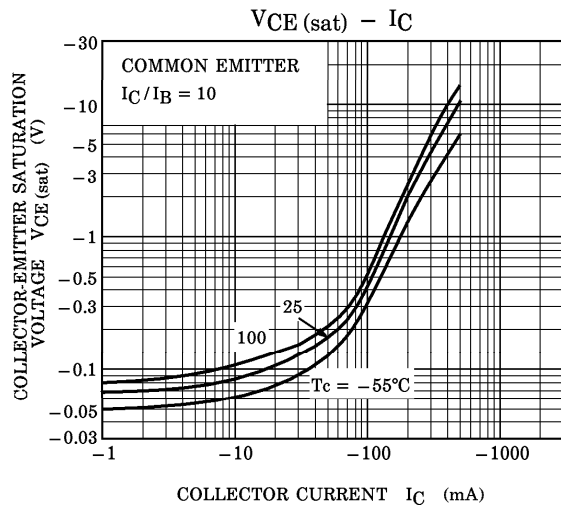
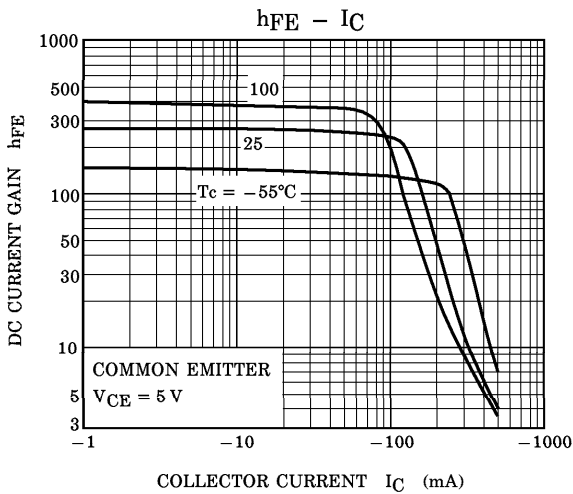
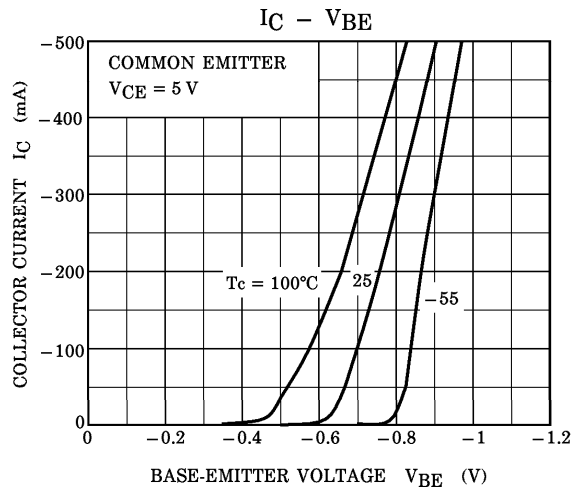
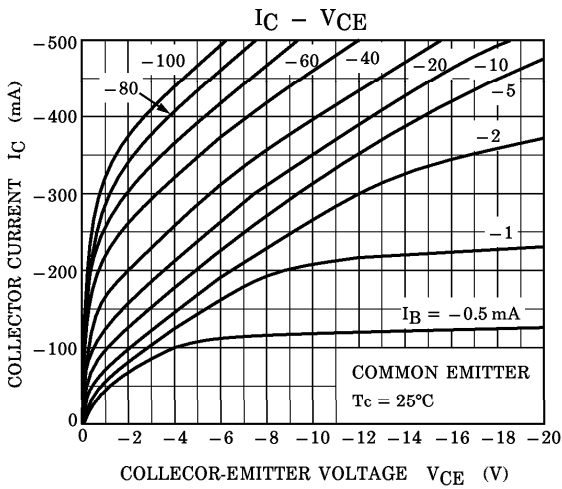
CHARACTERISTIC		SYMBOL	RATING	UNIT
Collector-Base Voltage		$V_{CB0}$	-400	V
Collector-Emitter Voltage		$V_{CEO}$	-400	V
Emitter-Base Voltage		$V_{EB0}$	-7	V
Collector Current	DC	$I_C$	-0.5	A
	Pulse	$I_{CP}$	-1	
Base Current		$I_B$	-0.25	A
Collector Power Dissipation	$T_a = 25^\circ\text{C}$	$P_C$	1	W
	$T_c = 25^\circ\text{C}$		10	
Junction Temperature		$T_j$	150	$^\circ\text{C}$
Storage Temperature Range		$T_{stg}$	-55~150	$^\circ\text{C}$

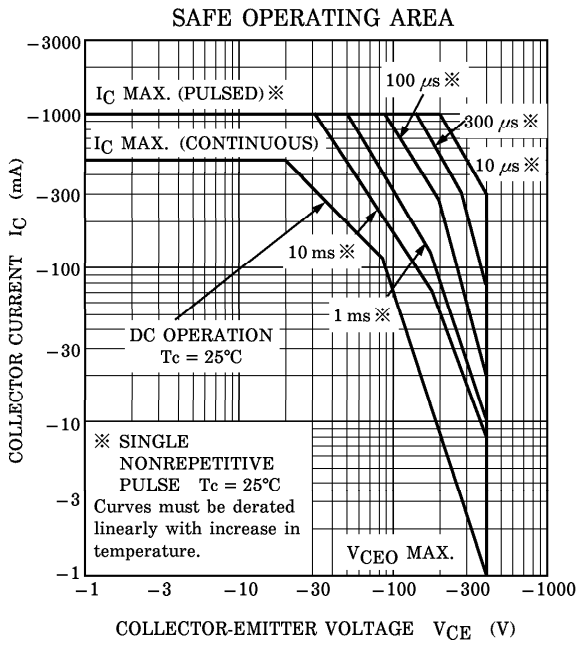
Unit in mm



ELECTRICAL CHARACTERISTICS (Tc = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current		ICBO	V <sub>CB</sub> = -400 V, I <sub>E</sub> = 0	—	—	-10	μA
Emitter Cut-off Current		IEBO	V <sub>EB</sub> = -7 V, I <sub>C</sub> = 0	—	—	-1	μA
Collector-Emitter Breakdown Voltage		V (BR) CEO	I <sub>C</sub> = -10 mA, I <sub>B</sub> = 0	-400	—	—	V
DC Current Gain		h <sub>FE</sub> (1)	V <sub>CE</sub> = -5 V, I <sub>C</sub> = -20 mA	140	—	450	
		h <sub>FE</sub> (2)	V <sub>CE</sub> = -5 V, I <sub>C</sub> = -100 mA	140	—	400	
Collector-Emitter Saturation Voltage		V <sub>CE</sub> (sat)	I <sub>C</sub> = -100 mA, I <sub>B</sub> = -10 mA	—	-0.4	-1.0	V
Base-Emitter Saturation Voltage		V <sub>BE</sub> (sat)	I <sub>C</sub> = -100 mA, I <sub>B</sub> = -10 mA	—	-0.76	-0.9	V
Transition Frequency		f <sub>T</sub>	V <sub>CE</sub> = -5 V, I <sub>C</sub> = -50 mA	—	35	—	MHz
Collector Output Capacitance		C <sub>ob</sub>	V <sub>CB</sub> = -10 V, I <sub>E</sub> = 0, f = 1 MHz	—	18	—	pF
Switching Time	Turn-on Time	t <sub>on</sub>	 <p> <math>I_{B1} = -10 \text{ mA}, I_{B2} = 20 \text{ mA},</math>  <math>\text{DUTY CYCLE} \leq 1\%</math> </p>	—	0.2	—	μs
	Storage Time	t <sub>stg</sub>		—	2.3	—	μs
	Fall Time	t <sub>f</sub>		—	0.2	—	μs





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